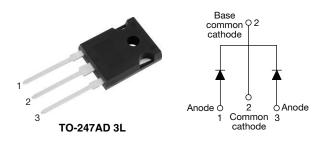
**Vishay Semiconductors** 

# Hyperfast Rectifier, 2 x 30 A FRED Pt® G5



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### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> , per leg	30 A					
V <sub>R</sub>	1200 V					
V <sub>F</sub> at I <sub>F</sub> at 125 °C	2.1 V					
t <sub>rr</sub>	26 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

### FEATURES

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

#### **MECHANICAL DATA**

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage, per leg	V <sub>RRM</sub>		1200	V		
Average rectified forward current, per leg	I <sub>F(AV)</sub>	T <sub>C</sub> = 101 °C, D = 0.50	30			
Repetitive peak forward current, per leg	I <sub>FRM</sub>	T <sub>C</sub> = 101 °C, D = 0.50, f = 20 kHz	60	А		
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C = 45 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	190			
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage, per leg	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	1200	-	-		
Forward voltage, per leg	V	I <sub>F</sub> = 30 A	-	2.6	3.3	V	
	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	2.1	-		
Deverse leakage everent ner leg		$V_{R} = V_{R}$ rated	-	-	50		
Reverse leakage current, per leg	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance, per leg	CT	V <sub>R</sub> = 200 V	-	17	-	pF	
Series inductance, per leg	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time, per leg		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	$I_F$ = 1.0 A, $dI_F/dt$ = 100 A/µs, $V_R$ = 30 V		26	57		
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	100	-	ns	
		T <sub>J</sub> = 125 °C		-	150	-		
Peak recovery current, per leg	1	$T_J = 25 \text{ °C}$ $I_F = 20 \text{ A}$	-	12	-	А		
Peak recovery current, per leg	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 600 A/µs V <sub>R</sub> = 400 V	-	22	-	~	
Poverse recovery charge, per leg	0	T <sub>J</sub> = 25 °C		-	530	-	nC	
Reverse recovery charge, per leg	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1650	-		
Poverse recovery time, per les	+	T <sub>J</sub> = 25 °C		-	80	-	ns	
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-		
Deale receiver a surrent per les		T <sub>J</sub> = 25 °C	$I_{\rm F} = 30  {\rm A}$	-	22	-	A	
Peak recovery current, per leg	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 1000 A/µs V <sub>B</sub> = 800 V	-	37	-		
	0	T <sub>J</sub> = 25 °C	1	-	900	-		
Reverse recovery charge, per leg	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	]	-	2400	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case, per leg	R <sub>thJC</sub>		-	-	0.8	°C/W		
10/-:			-	6	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Marking device		Case style TO-247AD 3L	C5PX6012L					

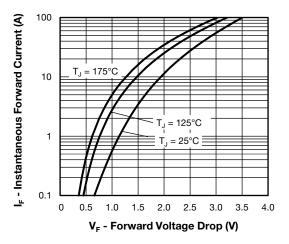
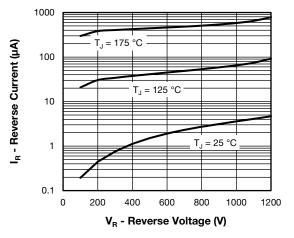
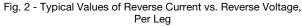


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg





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### VS-C5PX6012L-N3

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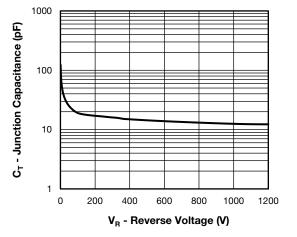


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

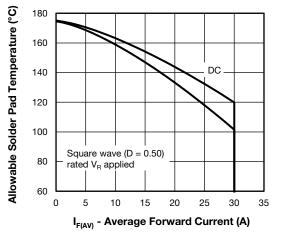


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

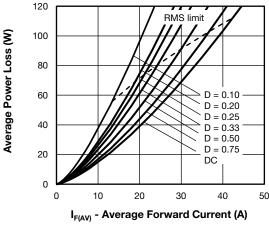


Fig. 5 - Typical Recovery Current vs. dl<sub>F</sub>/dt

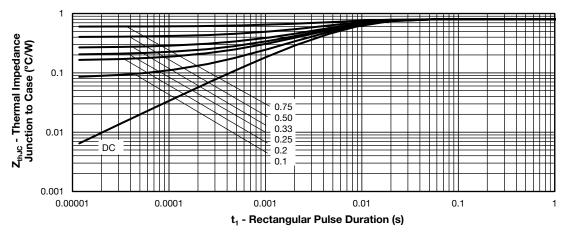


Fig. 6 - Forward Power Loss Characteristics, Per Leg

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## VS-C5PX6012L-N3

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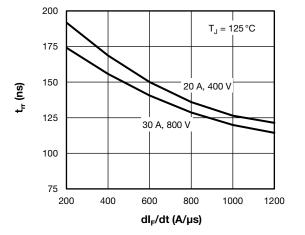


Fig. 7 - Transient Thermal Impedance, Junction to Case, Per Leg

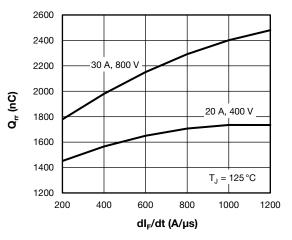


Fig. 8 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt, Per Leg

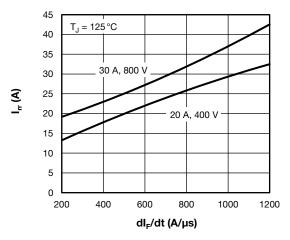


Fig. 9 - Typical Stored Charge vs. dl<sub>F</sub>/dt, Per Leg





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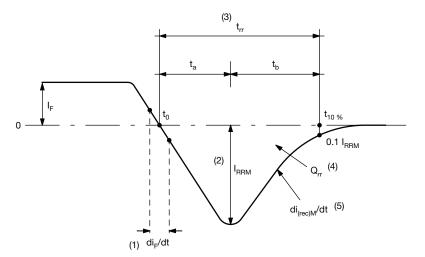


Fig. 10 - Reverse Recovery Waveform and Definitions

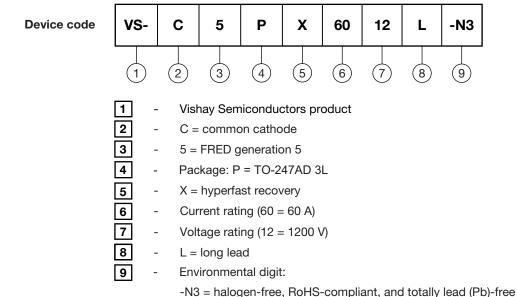
#### Notes

- $^{(1)}$  di<sub>F</sub>/dt rate of change of current through zero crossing
- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- <sup>(3)</sup>  $t_{rr}$  reverse recovery time measured from  $t_0$ , crossing point of negative going  $I_F$ , to point  $t_{10\%}$ , 0.1  $I_{RRM}$ <sup>(4)</sup>  $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

#### **ORDERING INFORMATION TABLE**



PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-C5PX6012L-M3	25	500	Antistatic plastic tube			
LINKS TO RELATED DOCUM	IENTS					
LINKS TO RELATED DOCOM	IEN I S	1				
Dimensions		www.vishay.com/doc?95626				
Part marking information		www.vishay.com/doc?95007				

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TO-247AD 3L

#### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215 BSC		
ØК	0.2	254	0.0	010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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